Non-generality of the K adow aki-W oods ratio in correlated oxides

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(D ated: today)

Abstract

An explicit expression for the K adow akiW oods ratio in correlated m etals is derived by invoking saturation of the (high-frequency) Ferm i-liquid scattering rate at the M ott-Io e-R egel lim it. Signi cant deviations observed in a num ber of oxides are quantitatively explained due to variations in carrier density, dim ensionality, unit cell volum e and the num ber of individual sheets in the B rillouin zone. A generic re-scaling of the original K adow aki-W oods plot is also presented.

O ne of the trium phs of Landau-Ferm i-liquid theory is its ability to encapsulate the physical calbehavior of a wide variety of m etals with only a limited set of parameters that characterize the many-body enhancement of the (quasiparticle) electrive mass. This enhancement manifests itself in a number of physical properties including the magnetic susceptibility $_{\rm P}$, the electronic speci cheat coe cient $_0$, the coe cient A of the T² resistivity and the slope of the low-T therm coelectric power S/T. In portant empirical relations correlating these quantities have been found, including the Kadowaki-Woods ratio (KWR) (A / $_0^2$ $_0$ = 10⁵

cm m of K^2/J^2) [1], the W ilson ratio ($_P / _0$ 1 T^2/K^2 for strongly-correlated ferm ions) [2] and m ost recently, the Behnia-Jaccard-F louquet ratio (S / $_0T$ 10⁶ C /m ol) [3].

In the original KW R paper [1], only heavy fem ion metals containing U and Ce were considered and most theoretical treatments to date have focussed on heavy fem ions and the dependence of A on the f-electron density of states [4, 5, 6, 7, 8]. Since then however, the ratio has been examined in a broad range of correlated metals and whilst the perception is one of generality, there are some notable exceptions, particularly among the oxides. As illustrated in Fig. 1a for example, $La_{1:7}Sr_{0:3}CuO_4$ [9], $Ca_{2 \times}Sr_xRuO_4$ [10, 11], $La_{1 \times}Sr_xTiO_3$ (x > 0.9) [12], LiV_2O_4 [13], V_2O_3 and $Na_{0:7}CoO_2$ [14] all show signi cant deviations from the empirical line A / $_0^2$ a. In this Letter, we show that whilst the KW R is largely insensitive to the strength of electron correlations from a for all those oxides listed above are qualitatively and quantitatively explained with a minimum of assumptions. Though we focus here on oxides, our approach is su ciently general as to encompass all correlated metals, including heavy fem ions, and a generic revision of the original KW scaling is proposed.

For a highly correlated Ferm i-liquid, one can neglect electron-phonon scattering and de ne a T - and !-dependent scattering rate of the form $_{FL}(T, !) = _{0} + ((p T)^{2} + !^{2})$, where $_{0}$ is the inpurity scattering rate, is a coe cient to be determined and p = 2 for electron-electron scattering [15]. This form for $_{FL}$ relects the phase space available for scattering and is appropriate at low energies. At higher energies how ever, the scattering rate m ust approach some maximum or 'saturated' value of order the bare bandwidth W. To account for this, we introduce a maximum scattering rate $_{max} = v_F /a$ (where v_F is the unrenormalized Ferm i velocity and a the lattice spacing) that is compatible with the

Mott-Io e-Regel limit, and de ne an e ective transport scattering rate $_{\rm e}$ (T, !) via

$$\frac{1}{e^{(T;!)}} = \frac{1}{F_{L}(T;!)} + \frac{1}{m_{ax}}$$
(1)

Inserting (1) into the D rude form ula for the dc conductivity, one obtains the well-known parallel-resistor form ula for saturating m etals [16]. M oreover, by including basal plane anisotropy in $_{\rm e}$ (T, !), this form of scattering rate can successfully account for both the dc and optical transport properties of optim ally doped cuprates [17, 18]. To sim plify our working, we make the identity = $_{\rm max} + _{0} + (2 \text{ T})^{2}$ and re-arrange $_{\rm e}$ to give $_{\rm e} = _{\rm max} - (_{\rm max}/)(1/(1 + ...)^{2})$. In this form, $_{\rm tr}$ (T, !) can be obtained analytically from the appropriate K ram ers-K ronig (K K) transform ation [19] with

$$tr (T;!) = {}^{2}_{max} (-)^{1=2} \frac{1}{(+!)^{2}}$$
(2)

Extrapolating to ! = 0 and low T where m_{ax} , we nally arrive at our expression for the dc m ass enhancem ent factor, $tr(0) = (m_{ax})^{1=2} = (v_F/a)^{1=2}$. Note that this mass enhancem ent is relative to the band m ass m_b as would be calculated, say, from LDA band calculations, and not the bare electron m ass m_0 . Finally, by converting to resistivity (T) $= _0 + AT^2 = m_b/ne^2(_0 + (2 T)^2)$ and re-instating all parameters, we obtain

$$A = \frac{4^{-2}k_{\rm B}^2}{e^2 h^2} \frac{{\rm am}_{\rm b}}{n} \left(\frac{{\rm tr}(0)^2}{v_{\rm F}} \right)$$
(3)

Note that A is proportional to $_{tr}(0)^2$ but also depends on $_{max}$ (v_F/a). This somewhat surprising result can be understood by acknow ledging that $_{max}$ sets the scale for $_e$ (!) to vary between its low – and high-frequency limits. This in turn, via the KK transformation, determ ines the enhancement in $_{tr}(0)$ as !! 0. $_{max}$ has in fact appeared in several previous derivations of A [6, 7, 20] though not in this form. M iyake et al. for example derived an expression for the KW R in heavy fermions assuming a strong frequency dependence of the quasi-particle lifetime (!) with saturation at the unitary limit [7]. Their treatment of saturation however did not allow for an analytical derivation of $_{tr}(0)$ and the resulting expression for A was markedly di erent from that given in (3).

The electronic speci c heat ∞ cient $_{\rm V} = 1/3 {}^{2}k_{\rm B}^{2} (1 + {}_{\rm th})^{\rm K} dS/4 {}^{3} h_{\rm F}$ where $(1 + {}_{\rm th})$ contains all contributions to the therm odynam ic mass enhancement m $/m_{\rm b}$, including electron-phonon coupling $_{\rm ph}$. Thus provided $_{\rm tr}(0) (1 + {}_{\rm th}) {}_{\rm ph}$, correlation e ects will cancel in the ratio A $/ {}_{\rm V}^{2}$ and the empirical scaling of the KWR in correlated metals

is obtained. (Conversely when $_{tr}(0)$ 1, the KWR will be substantially reduced.) For intermediate $_{tr}(0)$ (m m_b), the KWR will depend sensitively on know ledge of m_b and thus on the accuracy of the band calculations. In the following therefore, we choose to ignore the ratio $(_{tr}(0)/(1 + _{th}))^2$, adknow ledging that in most cases, this will lead to an overestim ate of the KWR. With this in mind, we now consider factors that might in uence the KWR and try to quantify their in pact on those oxides listed above.

E ect of unit cell volum e: Ever since K adowaki and W oods' sem inal paper [1], it has become custom any to plot the KWR with A expressed in units of cm/K^2 and $_0$ in $J/m olK^2$ (orm $J/m olK^2$), as illustrated in Fig. 1a. The electrical conductivity of a metal is the response function describing a current density J that is in turn related to a carrier density n expressed in units of m^3 . Hence, in its original form, the KWR compares a volum e quantity (A) with a molar quantity ($_0$). In order to compare the two quantities directly, we suggest it is more appropriate to express $_0$ in its volum e form $_V$ as given above. The two are scaled by the ratio N_AV/Z where N_A is A vogadro's number, V is the unit cell volum e and Z the number of form ula units per unit cell.

This seem ingly mute point, the choice of units, can have dram atic consequences. In the layered cobaltate $Na_{0.7}CcO_2$ for example, $A / \frac{2}{0}$ 50 a, almost two orders of magnitude larger than that seen in heavy-ferm ions [14] (see Fig.1a). This remarkable enhancement was naturally viewed as a signature of intense electron-electron scattering, possibly arising from magnetic flustration in the triangular lattice or proximity to a quantum critical point. Signi cantly however, $Na_{0.7}CcO_2$ has a tiny unit cell (hep lattice, a = 2.84A, c = 10.94A, $V = 76A^3$ and Z = 2). By contrast, in $La_{1.7}Sr_{0.3}CuO_4$, where Z = 1 in a unit cell is of comparable size (bot lattice, a = 3.86A, c = 6.4A, $V = 95A^3$), $A / \frac{2}{0}$ 5a [9]. If we now de ne a new parameter for the KW R, b = 1 cm K² cm $^6/J^2$, we nd for $Na_{0.7}CcO_2$, $A / \frac{2}{v} = 0.29b_0$ while for $La_{1.7}Sr_{0.3}CuO_4$, $A / \frac{2}{v} = 0.17b_0$. Hence, the one order of magnitude di erence in the two original KW R values can be attributed largely to the factor ($V / Z / ^2$. Fig.1b shows our revision of the KW plot in which A is compared with v rather than o. Note that the KW R for both V_2O_3 [14] and LiV_2O_4 [13] are also strongly renorm alized in this new scaling plot. These striking results serve to underline the importance of units, particularly when comparing compounds of very di erent chemical composition.

E ect of dimensionality: The dashed line in Fig. 1b corresponds to a nom inal KW R, A / $\frac{2}{V}$ = 0.2b₀. All compounds near this line are quasi-two-dimensional (quasi-2D) metals

Ferm i surface	A/ $_{\rm V}^2$ (10 ¹⁴ cm /K 2)/ (m J/cm 3 /K 2) ²
3D	$(108 \ ^4h/e^2k_B^2)$ (a/k_F^6) $(\frac{2}{tr}(0)/(1 + \frac{1}{th})^2)$
2D	(72 $h/e^2k_B^2$) (ac ³ /k _F ³) ($\frac{2}{tr}$ (0)/(1 + $\frac{1}{th}$) ²)
1D	(9 h/2e ² k _B ²) $ab^{3}c^{3}$ ($\frac{2}{tr}$ (0)/(1 + th) ²)

TABLE I: A / $\frac{2}{V}$ for spherical (3D), cylindrical (2D) and planar (1D) Ferm i surfaces.

whose physics is dominated by a single (large) cylindrical Ferm i surface (FS) (the one exception being $La_{0:05}Sr_{1:95}TiO_3$ to be discussed in the following section). Those compounds found below this line have either closed or multiple FS or a combination of the two. We note that whilst A depends on the FS volume (through n), v is largely governed by the FS area. Thus we expect the KWR to be sensitive to the FS geometry. Table 1 summarizes our derived KWR for spherical (3D), cylindrical (2D) and planar (1D) FS.Note that once we ignore the correlation term, there are no adjustable parameters in these expressions.

In order to compare directly with the KW R of real materials, detailed FS information is required. The FS of both $Na_{0:7}CoO_2$ and $La_{1:7}Sr_{0:3}CuO_4$ is found to be approximately cylindrical with radii of $k_F = 0.65$ and $0.55A^{-1}$ respectively [21, 22]. Inserting these values into our 2D expression for the KW R, we $nd A / V_V = 0.66b_0$ for $Na_{0:7}CoO_2$ and $0.3b_0$ for $La_{1:7}Sr_{0:3}CuO_4$. Thus, the enhanced KW R in both compounds can be adequately explained by consideration of the combined e ects of dimensionality and unit cell volume, without the need to invoke additional or exotic scattering.

E ect of carrier density: From Table 1 we see that the KW R in 1D m etals is independent of k_F , though not the unit cell dimensions. (Because of this, one expects the KW R to be extremely large in 1D organics). In 2D and 3D systems however, the KW R depends strongly on k_F . An idealmaterial to test this relation is La_{1 x} Sr_xT iO₃ for which n changes continuously for $0 \le x \le 1$. At x = 1, the system is close to being a band insulator, whilst for $x \le 0.05$, it is a M ott insulator. In between, the system exhibits m etallic transport characterized by a large T² resistivity that diverges at both ends of the series [12, 23].

The inset in Fig. 2 shows the KWR for $La_{1 x} Sr_x T iO_3$ near x = 0 (closed circles, reproduced from Ref. [23]). As indicated by the dashed line, A is NOT proportional to $\frac{2}{V}$. According to Table 1, one must also take into account the variation in n. If we assume the FS in $La_{1 x} Sr_x T iO_3$ to be spherical, we can write $1/k_F^6 = 1/(3^2n)^2$ and thus we expect

A / $\frac{2}{V}$ to be proportional to $1/n^2$ (the constant of proportionality here being m $(3 h/\hat{e}k_B^2)$ a where m accounts for the presence of multiple bands – see below). By re-plotting the data as A n² versus $\frac{2}{V}$ (black squares in the inset), linear scaling is indeed recovered. In the main panel, A / $\frac{2}{V}$ is plotted versus a/n^2 for a range of x values between 0 and 1 [12, 23]. The dashed line is the best t through the data set, the slope being m = 0.5. Rem arkably, the scaling appears to hold across the entire series with A / $\frac{2}{V}$ varying by 5 orders of m agnitude. P revious derivations of the KW R have contained some dependence on carrier num ber [4, 7, 8] but never as strong as that shown in Fig. 2. The persistence of KW scaling towards x = 1 is som ewhat surprising, but does suggest that electron correlations continue to play a prom inent role in the low-T transport behavior in La_{1 x} Sr_xT iO₃ right across the series.

Multiple band e ects: Signi cant deviations from the KWR are also expected when several bands cross the Ferm i level or when a single band is split into individual sheets. The key point here is that whilst bands contribute 'in series' to $_{\rm V}$, they add 'in parallel' to A. Obviously, when bands have di erent sizes and masses, the problem is rather complicated. P rovided these are known however, one can in principle obtain a quantitative estimate for A / $_{\rm V}^2$. To illustrate this point, we consider Sr₂RuO₄, perhaps the best characterized multiband oxide. The FS of Sr₂RuO₄ comprises three cylinders (, and) form ed from 4t_{eq} orbitals in the RuO₂ planes. The k_F and m values are 0.3, 0.62 and 0.75 (A⁻¹) and 3.3, 7.0 and 16.0 m₀ for , and respectively [24] while A = 4.5 - 7.5 n cm /K², $_{\rm V}$ = 0.66 m J/cm⁻³ K² and A / $_{\rm V}^2$ = 0.01 - 0.015b₀ [10], i.e. m ore than one order of magnitude sm aller than in Na_{0.7}C co₂ and La_{1.7}Sr_{0.3}C uO₄. Note that a sim ilar KWR is found in CaVO₃ (A / $_{\rm V}^2$ = 0.011b₀ [25]), whose FS has three inter-penetrating cylinders [26].

The speci c heat is most easily dealt with by re-writing the expression for $_{\rm V}$ in terms of m , i.e. $_{\rm V} = (k_{\rm B}^2/3\,{\rm h}^2{\rm c})_{\rm i}{\rm m}_{\rm i}$. Inserting the above masses, one nds $_{\rm V} = 0.67\,{\rm m}\,{\rm J/cm}^3\,{\rm K}^2$, in excellent agreement with experiment. From (3) (and assuming m m_b), the A coe cient for a single 2D cylinder is A_i (8 ${}^3{\rm ack}_{\rm B}^2/{\rm e}^2\,{\rm h}^3$). (m ${}_{\rm i}^2/{\rm k}_{\rm F}^3$), from which we obtain A = 12.4, A = 6.4 and A = 15.2 n cm/K². In order to estimate the magnitude of the combined A coe cient, we must assume that each sheet acts as an independent conduction channel. W hen the A_i coe cients are very large com pared to $_0$ (in the relevant tem perature range), one can simply apply the parallel-resistor form ula, i.e. $1/A = _{\rm i}1/A_{\rm i} = 3.6\,{\rm n}\,{\rm cm}/{\rm K}^2$. In the opposite limit ($_0$ AT²), the weighting of individual contributions to $_0$ should also

be taken into account via (see Appendix)

$$A = \frac{A \begin{pmatrix} 2 & 2 \\ 0 & 0 \end{pmatrix} + A \begin{pmatrix} 2 & 2 \\ 0 & 0 \end{pmatrix} + A \begin{pmatrix} 2 & 2 \\ 0 & 0 \end{pmatrix} + A \begin{pmatrix} 2 & 2 \\ 0 & 0 \end{pmatrix}}{(\begin{pmatrix} 0 & 0 \end{pmatrix} + \begin{pmatrix} 0 & 0 \end{pmatrix} + \begin{pmatrix} 0 & 0 \end{pmatrix} + \begin{pmatrix} 0 & 0 \end{pmatrix}}$$
(4)

where $_{0i} = (_{i}k_{Fi})/k_{Fi}$ for a 2D m etal. Eqn. (4) gives A = 5.2 n cm /K² for Sr₂RuO₄. Both estimates are comparable and agree well with experiment.

As an independent test of this picture, we consider $Ca_{2 x} Sr_x RuO_4$. For x < 0.5, quasiparticles on the and bands tend to localize, leaving only itinerant (and extrem ely heavy) quasiparticles on the large band [11]. At x = 0.2, $A / \frac{2}{V} = 0.18b_0$ [11]. Applying our single-band (2D) expression from Table 1 to $Ca_{1.8}Sr_{0.2}RuO_4$ (and assuming no change in the size of the -sheet), we obtain $A / \frac{2}{V} = 0.12b_0$. Hence, the very dimension of the two ruthenates can be qualitatively and quantitatively understood by addrow ledging the transition from multi- to single band physics with Ca doping. Proximity to the M ott insulating state is seen to induce negligible enhancement in $A / \frac{2}{V}$.

In sum m ary, we have derived explicit expressions for the KWR in correlated m etals in which m ass renorm alization is electively redundant. D eviations from the original KWR in a host of correlated oxides have been explained by careful consideration of the unit cell volume, dimensionality, carrier density and multi-band elects. Moreover, the importance of using appropriate units in plotting the KWR has been apply demonstrated. Though independent estimates of p (e.g. from optical conductivity) and a full microscopic derivation of Eqn. (3) are required, the overall consistency with experiment suggests that our assumption in (1) is valid and our expression for A m ay be used to gain additional information on the underlying physics in a variety of compounds.

W hen extending this scheme to other systems, additional e ects, such as disorder or orbital degeneracy (thought to play a key role in Yb-based compounds for example [8, 27]), should also be taken into account. In the light of all these complications, it is perhaps worth commenting on the perceived generality of the KWR, especially in heavy fermions. Though heavy fermions are mostly 3D compounds, tr(0) 1 and the unit cell is uniform ly large, the Fermi surfaces are complicated with num errous sheets of varying size and structure. Thus, their adherence to the KW scaling appears som ew hat puzzling. In order to reconcile this within the suggested fram ework, one must assume both A and v are dominated by a single surface (of heavy mass). Only when full FS information is available (i.e. that can account for the entire v) however, can the KWR be calculated for individual materials.

We therefore reserve a full discussion on the KWR in heavy ferm ions for a later date.

Finally, in line with Luttinger's theorem, we expect the KWR to remain constant as one varies W (but not n) and approach the M ott insulating state from the metallic side. This is supported by our quantitative explanation of the KWR in $Ca_{1:8}Sr_{0:2}RuO_4$. We argue that only when our revised form of the KWR is used (i.e. with the appropriate units), can genuine departures from the empirical scaling law, e.g. near a quantum critical point, be taken as evidence of novel physics. We hope this work stimulates a more rigorous approach to the physics of correlated metals and we welcome further quantitative comparisons on other systems in due course.

The author would like to thank J.C.A lexander, K.Behnia, A.Fujim ori, K.Kadowaki, H.Kontani, Y.Matsuda and H.Takagi for stimulating and enlightening discussions and EPSRC for their support. The author also acknow ledges the University of Tokyo for their hospitality during the course of this work.

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A coe cient in a 3-band quasi-2D m etal

The total conductivity $_{T} = + + is$ taken as the sum of individual contributions from each band. At 0K, one can assume an isotropic-' approximation and write,

$$_{0T} = \frac{e^2}{2 hc} \cdot_{0} \quad _{i}k_{F\,i} = \frac{1}{_{0T}} = \frac{_{0 \ 0} + _{0 \ 0} + _{0 \ 0} + _{0 \ 0}}{_{0 \ 0} \quad _{0 \ 0}}$$
(5)

At nite temperature, $_{i} = 1/(_{0i} + A_{i}T^{2})$ and so the change in conductivity is given by $_{i} = _{i} - _{0i} = -A_{i}T^{2}/_{0i}(_{0i} + A_{i}T^{2}) - A_{i}T^{2}/_{0i}^{2}$ provided $_{0i} - A_{i}T^{2}$. Thus,

$$T_{T} = \left(\frac{A}{\binom{2}{0}} + \frac{A}{\binom{2}{0}} + \frac{A}{\binom{2}{0}}\right)T^{2} = \left(\frac{A}{\binom{2}{0}} + \frac{2}{\binom{2}{0}} + A + \frac{2}{\binom{2}{0}} + \frac{2}{\binom{2}{0}} + A + \frac{2}{\binom{2}{0}} + \frac{2}{\binom{2}{0}}\right)T^{2}$$
(6)

Since $_{T} / _{0T} = - _{T} / _{0T}$, the total change in resistivity $_{T} = AT^{2}$ with A as given in (4). This can of course be generalized to an n-band m etal or to other dimensions.

- [2] K.W ilson, Proc. Nobel Sym posium XXIV, K.Yam ada, Prog. Theor. Phys. 53, 970 (1975).
- [3] K.Behnia, D.Jaccard and J.Flouquet, J.Phys.Cond.Mat. 16, 5187 (2004).

^[1] K.Kadowakiand S.B.Woods, Solid State Comm. 58, 507 (1986).

- [4] K.Yam ada and K.Yosida, Prog. Theor. Phys. 76, 621 (1986).
- [5] A.Auerbach and K.Levin, J.Appl. Phys. 61, 3162 (1987).
- [6] P.Coleman, Phys. Rev. Lett. 59, 1026 (1987).
- [7] K.Miyake, T.Matsuura and C.M.Varma, Solid State Comm. 71, 1149 (1989).
- [8] H.Kontani, J.Phys. Soc. Japan 73, 515 (2004).
- [9] S.Nakam ae et al, Phys. Rev. B 68, 100502 (R) (2003).
- [10] Y.Maeno et al, J.Phys.Soc.Japan 66, 1405 (1997).
- [11] S.Nakatsujiet al, Phys.Rev.Lett. 90, 137202 (2003).
- [12] T.Okuda et al, Phys. Rev. B 63, 113104 (2001).
- [13] C.Urano et al, Phys. Rev. Lett. 85, 1052 (2000).
- [14] S.Y.Lietal, Phys.Rev.Lett. 93, 056401 (2004).
- [15] R.N.Gurzhi, Zh.Eksp.Teor.Fiz. 35, 965 (1958) [Sov.Phys.-JETP 8, 673 (1959)].
- [16] N.E.Hussey, K. Takenaka and H. Takagi, Phil. M ag. 84, 2847 (2004).
- [17] N.E.Hussey, Euro.Phys.J.B 31, 495 (2003).
- [18] N.E.Hussey and J.C.Alexander, unpublished.
- [19] A.V.Puchkov, D.N.Basov and T.Timusk, J.Phys.Cond.Mat. 8, 10049 (1996). Note that FL (T, !) alone fails to satisfy the causality relation for (T, !).
- [20] T.C.Liand J.W. Rasul, Phys. Rev. B 39, 4630 (1989).
- [21] M.Z.Hasan et al, Phys.Rev.Lett. 92, 246402 (2004).
- [22] A. Ino et al, Phys. Rev. B 68, 094504 (2002).
- [23] Y. Tokura et al, Phys. Rev. Lett. 70, 2126 (1993).
- [24] C.Bergem ann et al, Adv.Phys. 52, 639 (2003).
- [25] I.H. Inoue et al, Phys. Rev B 58, 4372 (1998).
- [26] I.H. Inoue et al, Phys. Rev. Lett. 88, 236403 (2002).
- [27] N.Tsujii, K.Yoshim ura and K.Kosuge, J.Phys.Cond.Mat.15, 1993 (2003).

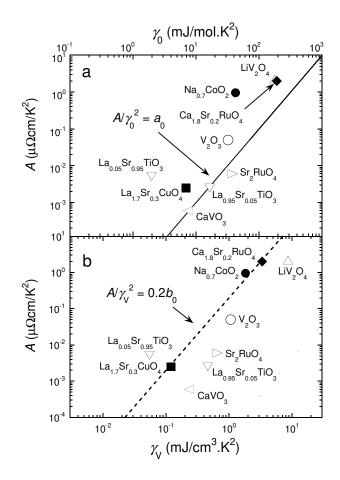


FIG.1: a. O riginal K adow aki-W oods plot (A versus $_0^2$) for selected correlated oxides (a₀ = 10⁵ cm K² m of²/J²). b: A versus $_V^2$ for the same compounds (b₀ = 1 cm K² cm ⁶/J²).

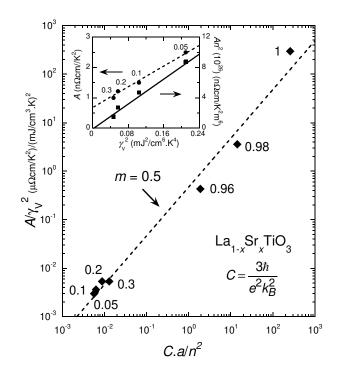


FIG.2: A / $_{\rm V}^2$ versus C a/n² for La_{1 x} Sr_xT iO₃. The parameter C is given in the gure. Each data point is labelled by the appropriate x value. Inset: C losed circles: A versus $_{\rm V}^2$ for La_{1 x} Sr_xT iO₃ near x = 1. B lack squares: A n² versus $_{\rm V}^2$. The lines are guides to the eye.